

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, uniotificated use, even if such claim any manner.



FQD6N50C N-Channel QFET[®] MOSFET

500 V, 4.5 A, 1.2 Ω

Features

- 4.5 A, 500 V, $R_{DS(on)}$ = 1.2 Ω (Max.) @V_{GS} = 10 V, I_D = 2.25 A
- Low Gate Charge (Typ. 19 nC)
- Low Crss (Typ.15 pF)
- 100% avalanche tested

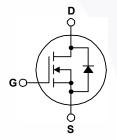
November 2013



Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.





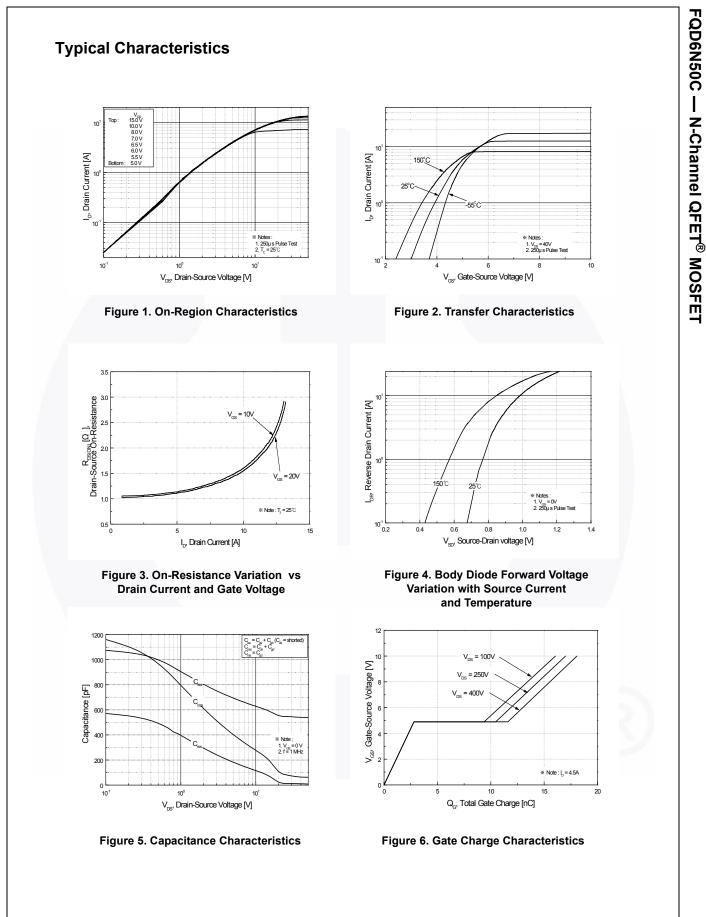
Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

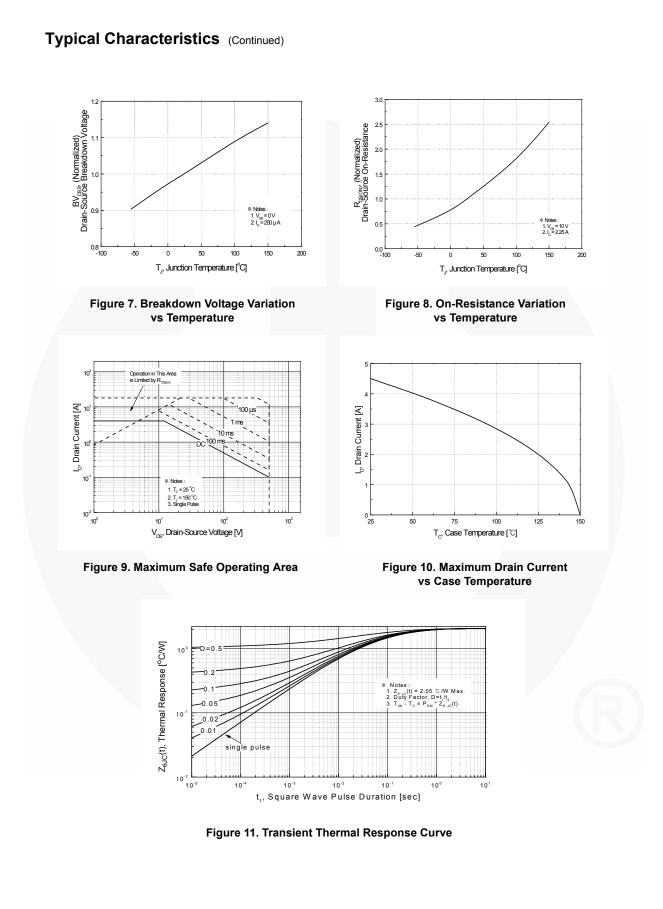
Symbol	Parameter		FQD6N50CTM	Unit
V _{DSS}	Drain-Source Voltage		500	V
I _D	Drain Current - Continuous (T _C = 25°C)		4.5	A
	- Continuous (T _C = 100°C)		2.7	А
I _{DM}	Drain Current - Pulsed	(Note 1)	18	А
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		300	mJ
I _{AR}	Avalanche Current	(Note 1)	4.5	A
E _{AR}	Repetitive Avalanche Energy		6.1	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns
	Power Dissipation (T _A = 25°C)*		2.5	W
P _D	Power Dissipation (T _C = 25°C)		61	W
	- Derate above 25°C		0.49	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

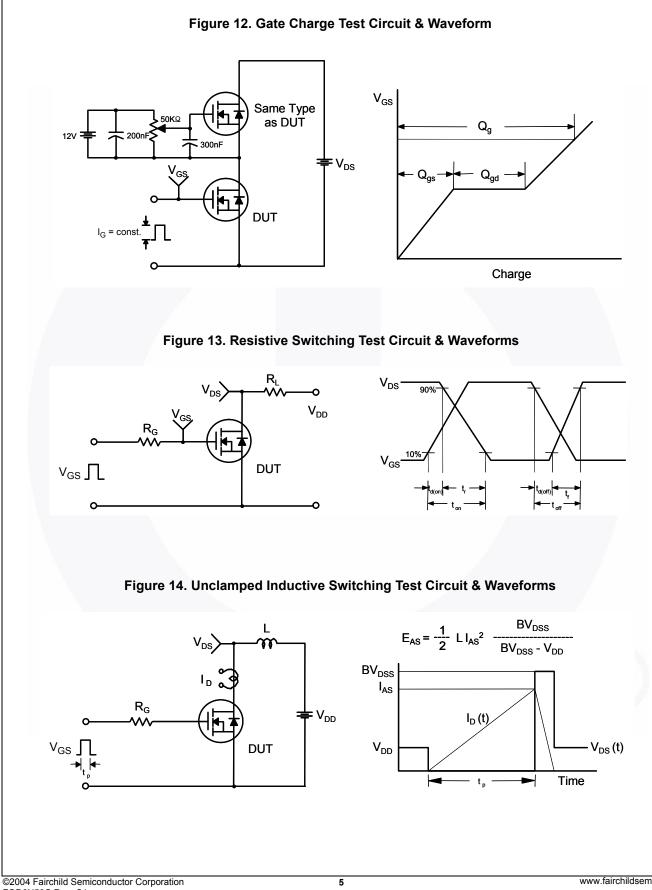
Thermal Characteristics

Symbol	Parameter	FQD6N50CTM	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	2.05	
$R_{ heta JA}$	Thermal Resistance, Junction-to-Ambient (minimum pad of 2 oz copper), Max.	110	°C/W
	Thermal Resistance, Junction-to-Ambient (* 1 in ² pad of 2 oz copper), Max.	50	

Device MarkingDeviceFQD6N50CFQD6N50CTM		Package	Package Reel Size		Width	Qua	Quantity	
		D-PAK 330 mm		16 mm		2500 units		
lectri	cal Char	acteristics T _C = 25°C	C unless otherwise	noted.				
Symbol		Parameter	Test Conditions		Min	Тур	Max	Unit
Off Cha	aracteristi	6						
BV _{DSS}		ce Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA		500			V
ABV _{DSS}		Voltage Temperature	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C					
ΔTJ	Coefficient	i i i i i i i i i i i i i i i i i i i				0.8		V/°C
	Zero Gate Voltage Drain Current		V _{DS} = 500 V, V _{GS} = 0 V				1	μA
DSS			V_{DS} = 400 V, T_{C} = 125°C				10	μA
GSSF	Gate-Body	Leakage Current, Forward	V_{GS} = 30 V, V_{DS}	= 0 V			100	nA
GSSR	Gate-Body	Leakage Current, Reverse	V_{GS} = -30 V, V_{DS}	_S = 0 V			-100	nA
On Cha	racteristi	cs						
/ _{GS(th)}		hold Voltage	V _{DS} = V _{GS} , I _D = 250 μA		2.0		4.0	V
R _{DS(on)}	Static Drair On-Resista		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.25 \text{ A}$			1.0	1.2	Ω
FS	Forward Tr	ansconductance	V _{DS} = 40 V, I _D =	2.25A		4.5		S
-	ic Charac						1	t
Piss	Input Capa		V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz			540	700	pF
Soss	Output Cap					80	105	pF
rss	Reverse Tr	ansfer Capacitance				15	20	pF
Switch	ing Chara	cteristics						
d(on)	Turn-On Delay Time $V_{DD} = 250 \text{ V}, \text{ I}_{D} = 4.5 \text{ A},$			10	30	ns		
r	Turn-On Ri	se Time	$R_G = 25 \Omega$			35	80	ns
d(off)	Turn-Off De	elay Time				55	120	ns
	Turn-Off Fa	all Time		(Note 4)		45	100	ns
ζ ^g	Total Gate	Charge	V _{DS} = 400 V, I _D = 4.5A,			19	25	nC
۵ _{gs}	Gate-Source	ce Charge	V _{GS} = 10 V			2.8		nC
ک _{gd}	Gate-Drain	Charge	(Note 4)			8.8		nC
Drain-S	ource Dic	ode Characteristics a	nd Maximum F	Ratings				
S	Maximum (Continuous Drain-Source Dic	de Forward Curre	nt			4.5	Α
SM	Maximum F	Pulsed Drain-Source Diode F	orward Current				18	Α
' _{SD}	Drain-Sour	ce Diode Forward Voltage	V_{GS} = 0 V, I _S =	4.5 A			1.4	V
rr	Reverse Re	ecovery Time	$V_{GS} = 0 V, I_S = 4.5 A,$			260		ns
ک ^{رر}	Reverse Re	ecovery Charge	dI _F / dt = 100 A/µ	IS		1.6		μC
	-	h limited by maximum junction tempe $_{\rm D}$ = 50V, R _G = 25 Ω, starting T _J = 25°(







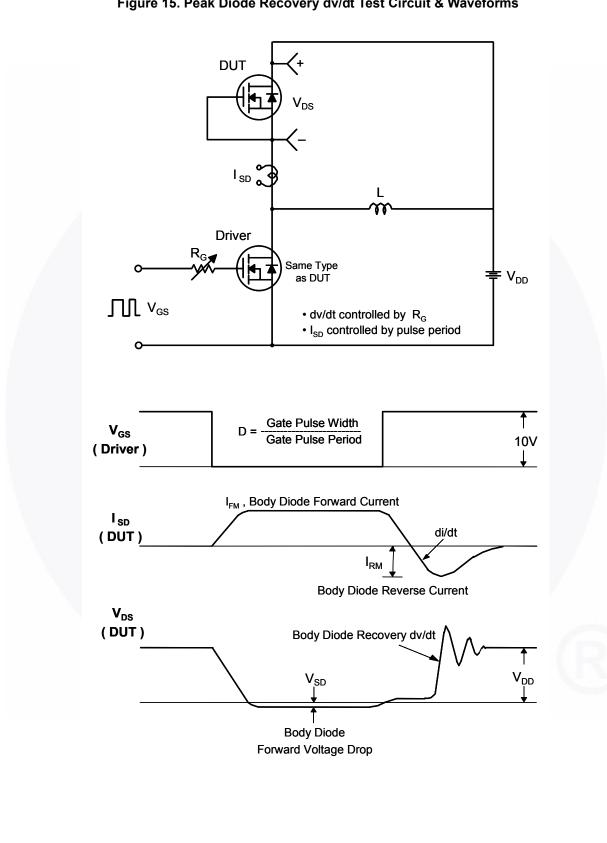
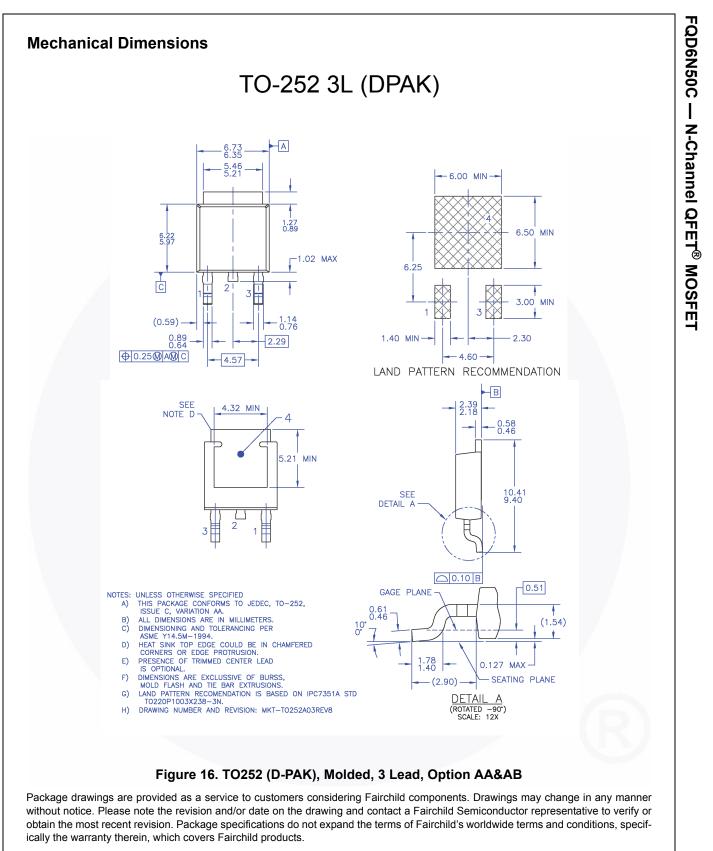


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TT252-003

Dimension in Millimeters



SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™	F-PFS™_	-45	Sync-Lock™
AX-CAP [®] *	FRFET®		SYSTEM ®*
BitSiC™	Global Power Resource SM	PowerTrench [®]	GENERAL
Build it Now™	GreenBridge™	PowerXS™	TinyBoost [®]
CorePLUS™	Green FPS™	Programmable Active Droop™	TinyBuck [®]
CorePOWER™	Green FPS™ e-Series™	QFET®	TinyCalc™
CROSSVOLT™	Gmax™	QS™	TinyLogic®
CTL™	GTO™	Quiet Series™	TINYOPTO™
Current Transfer Logic™	IntelliMAX™	RapidConfigure™	TinyPower™
DEUXPEED®	ISOPLANAR™		TinyPWM™
Dual Cool™	Marking Small Speakers Sound Loude		TinyWire™
EcoSPARK [®]	and Better™	Saving our world, 1mW/W/kW at a time™	TranSiC™
EfficentMax™	MegaBuck™	SignalWise™	TriFault Detect™
ESBC™	MICROCOUPLER™	SmartMax™	TRUECURRENT®*
F R	MicroFET™	SMART START™	µSerDes™
<i>t</i>	MicroPak™	Solutions for Your Success™	
Fairchild [®]	MicroPak2™	SPM [®]	SerDes™
Fairchild Semiconductor [®]	MillerDrive™	STEALTH™	UHC [®]
FACT Quiet Series™	MotionMax™	SuperFET®	Ultra FRFET™
FACT®	mWSaver®	SuperSOT™-3	UniFET™
FAST [®]	OptoHiT™	SuperSOT™-6	VCX™
FastvCore™	OPTOLOGIC®	SuperSOT™-8	VisualMax™
FETBench™	OPTOPLANAR®	SupreMOS®	VoltagePlus™
FPS™		SyncFET™	XS™
			7.0

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

FQD6N50C Rev. C1

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC